A novel mesoscopic phenomenon: An analog of the Braess paradox in 2DEG networks

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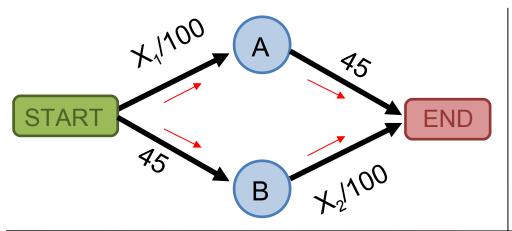
Outline

- Braess paradox in classical networks
- Simulations of a quantum network
- Simulations of scanning gate experiments
- SGM experiments on a real network



The original Braess paradox for road networks

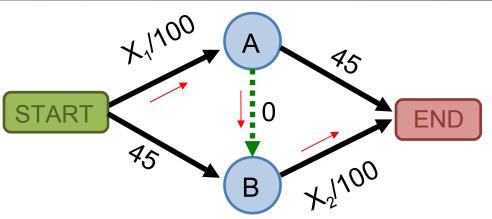
Braess (1968): Adding extra road to a **congested** network, where the moving entities freely choose their route, can in **some** cases reduce overall performance.



 $X = X_1 + X_2 =$ **4000 drivers** want to go from **START** to **END** while freely choosing their way

(Nash) equilibrium : $X_1 = X_2 = 2000$

Total travel time for each driver = 65 min



A high-speed road with **0 min** travel time is opened from A to B

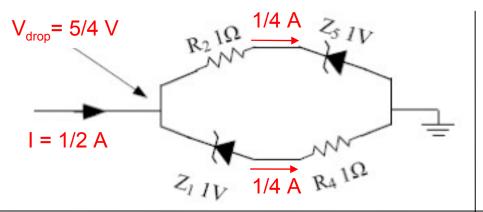
New (Nash) equilibrium : all drivers choose the **Start > A > B > End** road : $X_1 = X_2 = 4000$

Travel time for each driver = 80 min !!!



Braess paradox in electrical networks

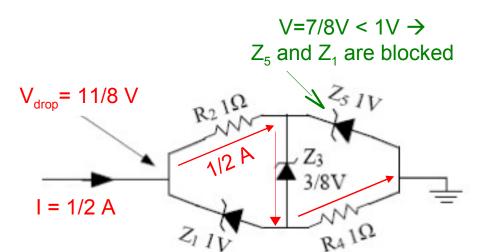
See: Cohen & Horowitz, Nature (1991) and Penchina & Penchina, Am. J. Phys. (2003)



A Wheastone bridge with **non-linear** Zener diodes at constant current = 1/2 A

At equilibrium, a 1/4 A current flows in each branch: voltage drop = 5/4 V

$$Z = 2.5 \Omega$$



An additional (lower-voltage) Zener bypasses the two branches.

At equilibrium, the entire current flows along red arrows (1V Zener diodes are blocked): voltage drop = 11/8 V > 5/4 V

$$Z = 2.75 \Omega$$



Braess paradox : offering a new path to current increases impedance.

Note: If only linear components are used, no paradox occurs.

Braess paradox in the quantum world ???

Known so far for classical networks only (road, electric, hydraulic, thermal)

we propose to extend the Braess paradox to the quantum world

using quantum simulations and Scanning Gate Microscopy

M.G. Pala et al., Physical Review Letters 108, 076802 (2012)

M.G. Pala et al., Nanoscale Research Letters 7, 472 (2012)



Rectangular corral:

 $L_x \times L_y = 1.0 \times 1.6 \mu m^2$

openings: $W_0 = 300 \text{ nm}$

vertical wires: $W_0 = 300 \text{ nm}$

horizontal wires: W₁ = 100 nm

Fermi wavelength: 20 nm

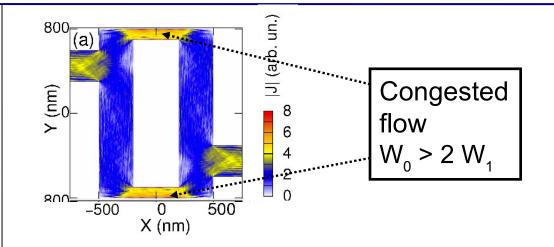
Ballistic and coherent regime :

L ≤ mean-free path & coherence length

Quantum simulations of the current density distribution :

$$|\mathbf{J}|(X, Y)$$

at T = 4.2 K and V_{bias} = 1 mV Keldysh-Green's function formalism Marco Pala @ IMEP (Grenoble)





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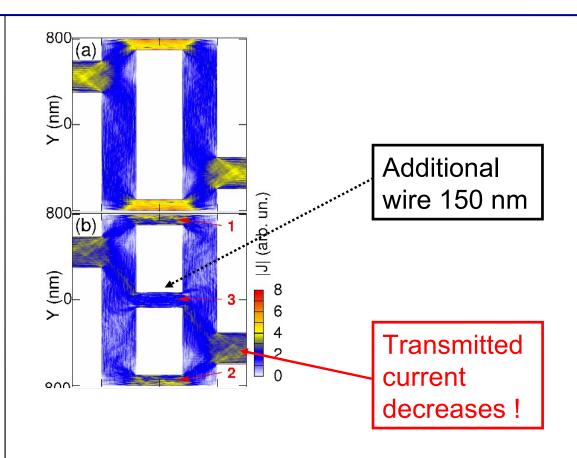
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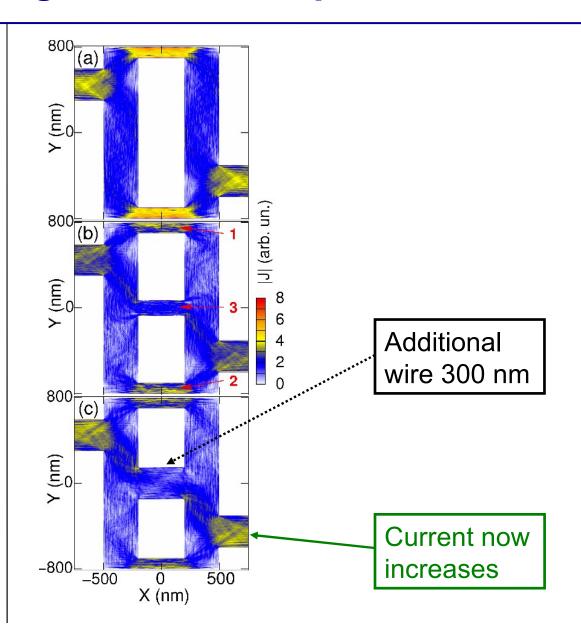
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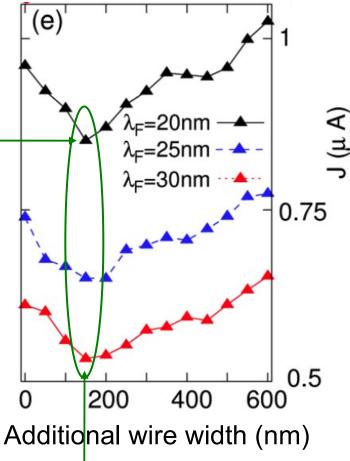




Total transmitted current for different Fermi wavelengths

The total current drops when additional channels are added to the network:

→ a Braess like paradox!



The current minimum is at the same width irrespective of λ_{E} :

→ NOT a quantum interference effect!



How to measure the effect?

Patterning a series of devices with different widths would give anoying mesoscopic fluctuations...

It would be better to use a single device with a flying nanoscale gate :

→ Scanning Gate Microscopy !!!



Introduction to SGM

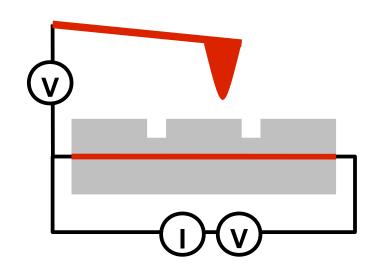
Local probe of electron properties in semiconductor heterostructures

where electrons are several tens of nanometers below the surface thus not accessible by Scanning Tunneling Microscopy

SGM requires Atomic Force Microscopy techniques for tip positioning

• Quantum Point Contact
• Quantum Wire
• Quantum Dot
• Quantum Ring

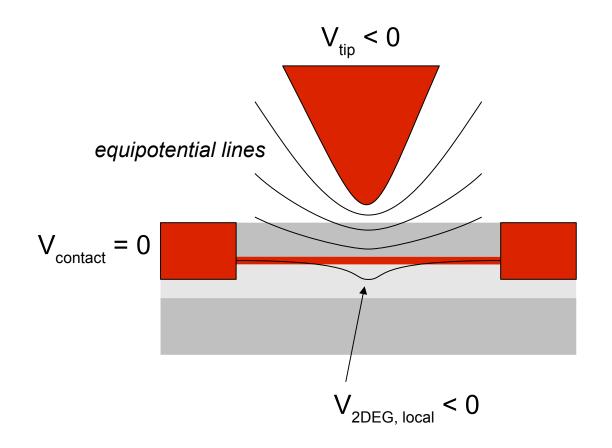
Quantum Hall Effect





Introduction to SGM

Low density electron gas ⇒ imperfect screening of the tip potential ⇒ local potential change ⇒ modified electron scattering ⇒ conductance change



Other ingredients:
Contact potential
Dielectric constants
Etched trenches
Surface gates
Charged defects



Sample parameters:

openings: W₀ = 300 nm

horizontal wires : W₀' = 180nm

side arms : $W_1 = W_2 = 140 \text{ nm}$

central arm : W₃ = 160 nm

Fermi wavelength = 47 nm

device bias = 1 mV

Tip parameters:

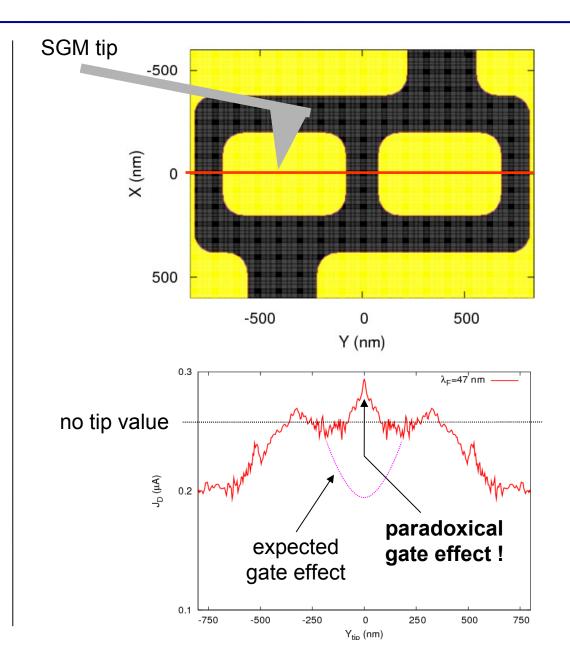
 $V_{tip} = -1 V$

 $d_{tip} = 100 \text{ nm}$

Full 2DEG depletion under the tip (about 300 nm diameter)

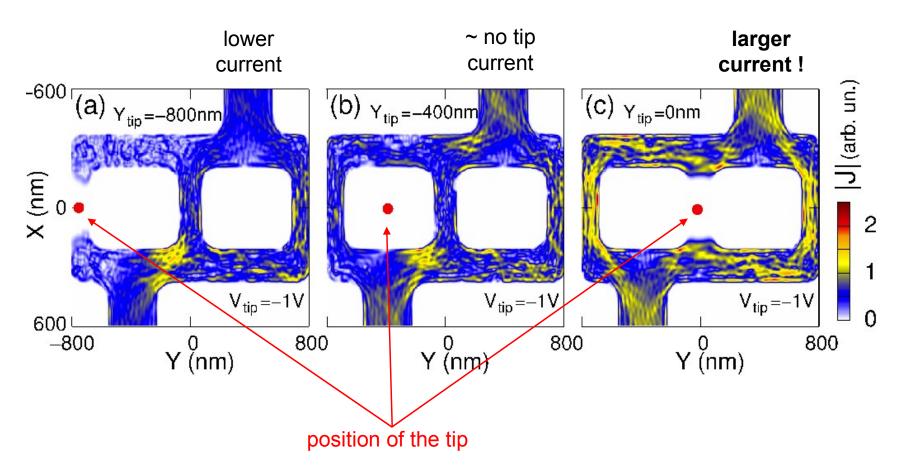
Result:

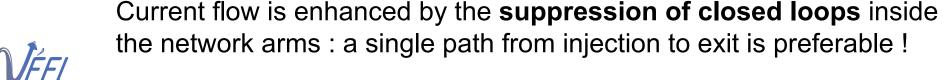
Current peak above the no tip value Only at the central arm Large effect (larger than UCF)



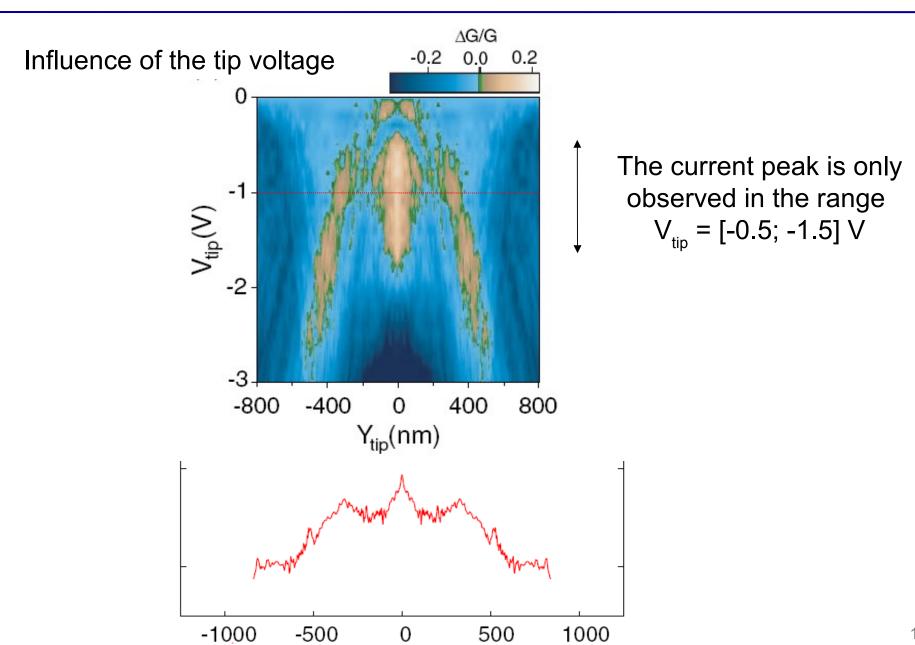


Current density distribution : $|\mathbf{J}|(X, Y)$



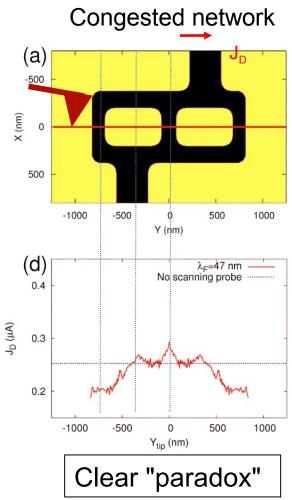


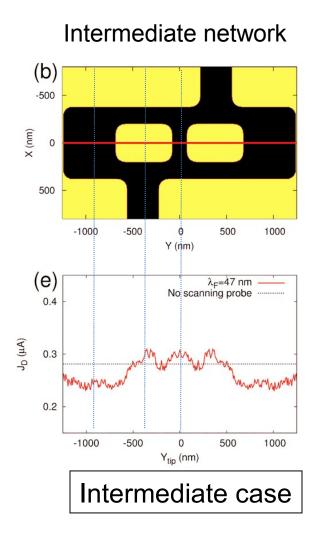


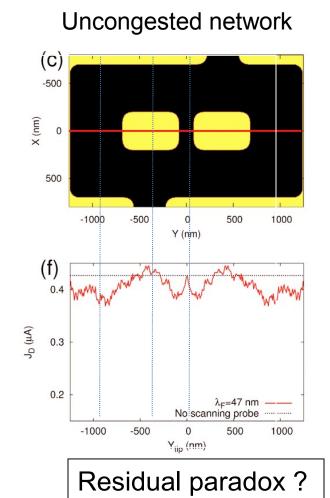




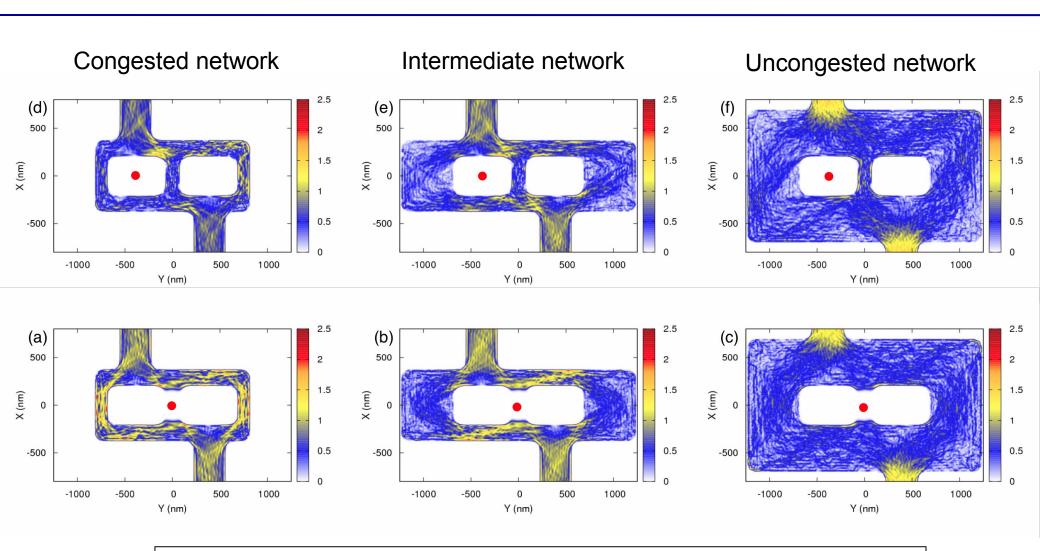
Role of congestion in the side arms







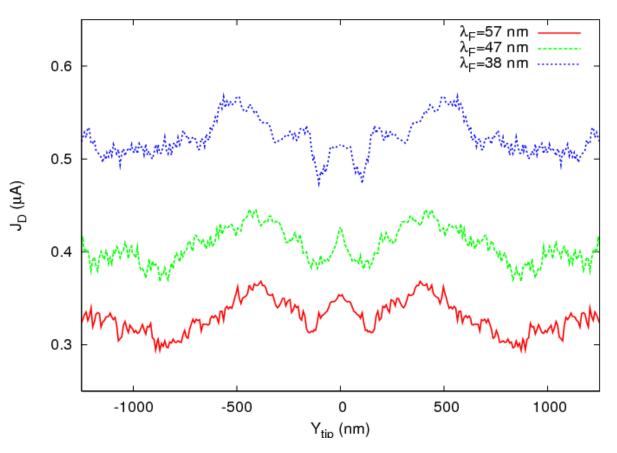






The current peak can be visualized in the current density maps only for the congested network

Uncongested network : influence of Fermi wavelength



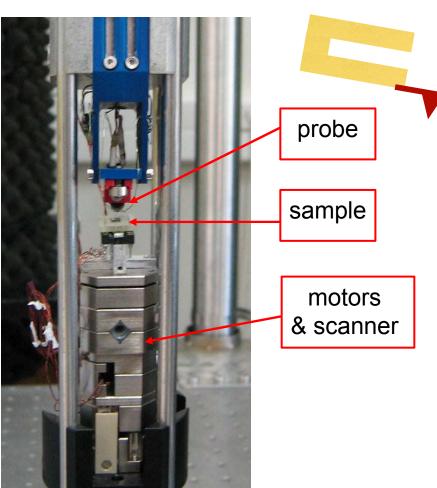
A current peak is always visible when the tip is exactly above the central arm : larger transmission for a perfectly symmetric structure rather than a chaotic one



SGM experiments : microscope

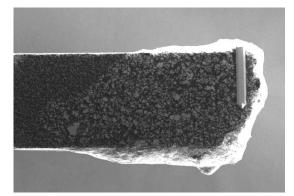
AFM @ 4 K and up to 11 T in Grenoble

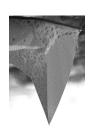
also available : 20 mK and up to 17 T in Louvain-la-Neuve



Probe = conductive AFM cantilever glued to a metallic pad of a tuning fork

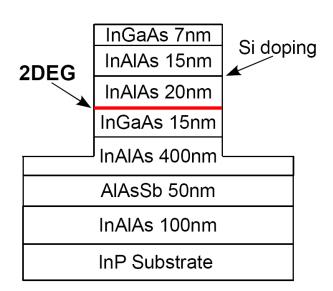






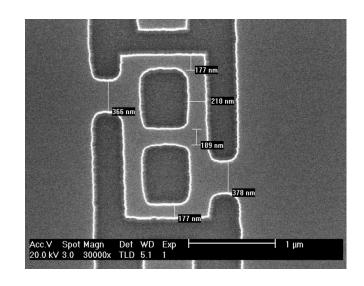


SGM experiments : device

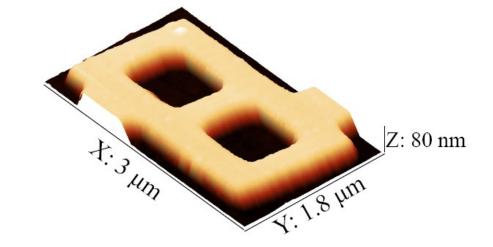


Collaborative work:

- growth (IEMN)
- lithography (UCL)
- AFM+SGM (NEEL)

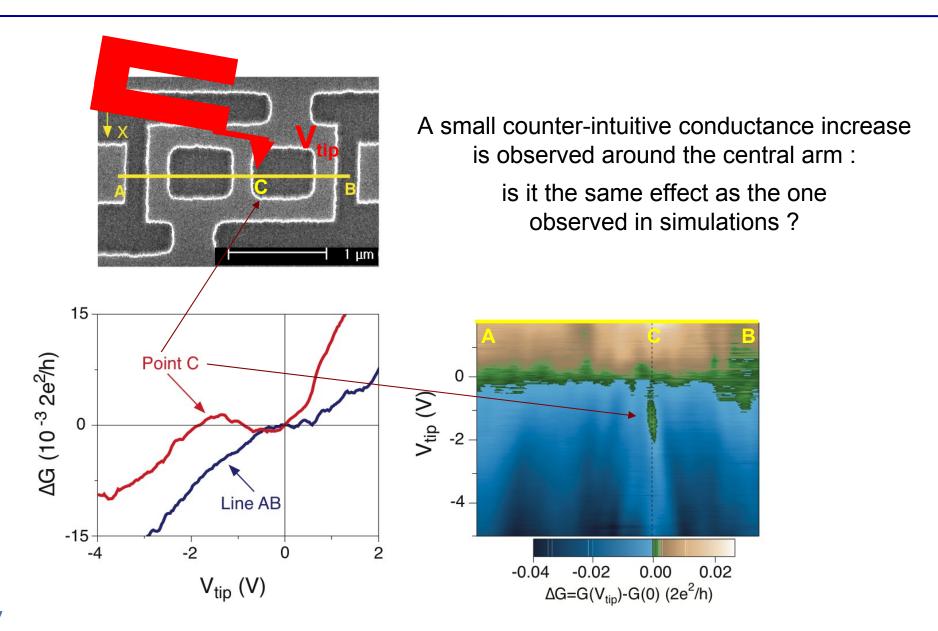


2DEG properties: density = 3.5×10^{11} cm⁻² mobility = $100\ 000$ cm²/V/s Fermi wavelength = 42 nm





SGM experiments : Braess paradox





Conclusions

A Braess-like paradox has been evidenced in simulations of mesoscopic networks :

- Closing a by-passing path can increase transport efficiency!
- Microscopic origin seems linked to current redistribution inside the network.

Many open questions:

- How far the analogy with the classical paradox can be made?
- What is the best suited geometry?
- Role of phase coherence and/or ballistic transport?
- Role of weak localization and interference?
- Influence of a magnetic field?

More experiments are needed!













Thank you for your attention!













